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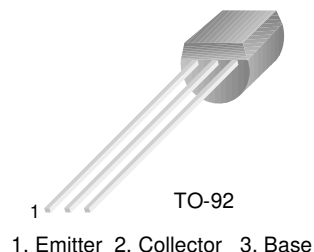


2N3702

2N3702

PNP General Purpose Amplifier

- This device designed for use as general purpose amplifier and switches requiring collector currents to 300mA.
- Sourced from Process 68.
- See PN200 for Characteristics.



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings* $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	-25	V
V_{CBO}	Collector-Base Voltage	-40	V
V_{EBO}	Emitter-Base Voltage	-5.0	V
I_C	Collector Current - Continuous	-500	mA
T_J, T_{ST}	Operating and Storage Junction Temperature Range	-55 ~ +150	$^\circ\text{C}$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
Off Characteristics						
$BV_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = -10\text{mA}, I_B = 0$	-25			V
$BV_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = -100\mu\text{A}, I_E = 0$	-40			V
$BV_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = -100\mu\text{A}, I_C = 0$	-5.0			V
I_{CBO}	Collector Cut-off Current	$V_{CB} = -20\text{V}, I_E = 0$			-100	nA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = -3.0\text{V}, I_C = 0$			-100	nA
On Characteristics *						
h_{FE}	DC Current Gain	$V_{CE} = -5.0\text{V}, I_C = -50\text{mA}$	60		300	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -50\text{mA}, I_B = -5.0\text{mA}$			-0.25	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$V_{CE} = -5.0\text{V}, I_C = -50\text{mA}$	-0.6		-1.0	V
Small Signal Characteristics						
C_{ob}	Current Gain Bandwidth Product	$V_{CB} = -10\text{V}, f = 1.0\text{MHz}$			12	pF
f_T	Output Capacitance	$I_E = -50\text{mA}, V_{CE} = -5.0\text{V}$	100			MHz

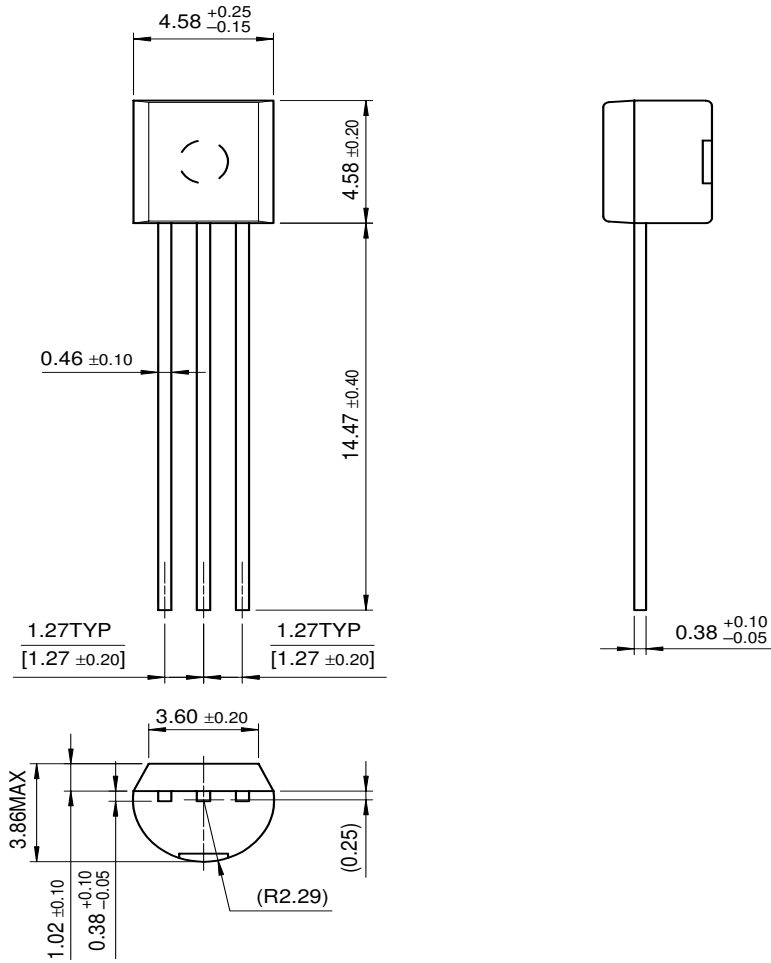
* Pulse Test: Pulse $\leq 300\mu\text{s}$, Duty Cycle $\leq 2.0\%$

Thermal Characteristics $T_A=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max.	Units
P_D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/ $^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	$^\circ\text{C}/\text{W}$

Package Dimensions

TO-92



Dimensions in Millimeters

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Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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